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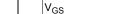


ON Semiconductor®

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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

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Parameter		Q1	Q2	Units
Drain to Source Voltage		20	20	V
Gate to Source Voltage		±12	±12	V
-Continuous		4		^
-Pulsed		1	0	A
Power Dissipation (Steady State) Q1 (Note 1a)		1.92		w
Power Dissipation (Steady State) Q2		1.	vv	
Operating and Storage Junction Temperature Range		-55 to	+150	°C
	Drain to Source Voltage Gate to Source Voltage -Continuous -Pulsed Power Dissipation (Steady State) Q1 Power Dissipation (Steady State) Q2	Drain to Source Voltage Gate to Source Voltage -Continuous -Pulsed Power Dissipation (Steady State) Q1 Power Dissipation (Steady State) Q2	Drain to Source Voltage 20 Gate to Source Voltage ±12 -Continuous 4 -Pulsed 1 Power Dissipation (Steady State) Q1 (Note 1a) Power Dissipation (Steady State) Q2 1.	Drain to Source Voltage 20 20 Gate to Source Voltage ±12 ±12 -Continuous 4 -Pulsed 10 Power Dissipation (Steady State) Q1 (Note 1a) 1.92 Power Dissipation (Steady State) Q2 1.78

Thermal Characteristics

_						
R	R _{0JA}	Thermal Resistance, Junction to Ambient	Q1	(Note 1a)	65	°C/W
R	Rella	Thermal Resistance, Junction to Ambient	Q2		70	0/10

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
6890N	FDMC6890NZ	Power 33	7inch	8mm	3000 units

General Description

DC converters with excellent

unclamped voltage input. Application

DC - DC Conversion



Features

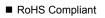
FAIRCHILD SEMICONDUCTOR

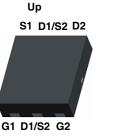
Q1: N-Channel

- Max $r_{DS(on)}$ = 68m Ω at V_{GS} = 4.5V, I_D = 4A
- Max r_{DS(on)} = 100mΩ at V_{GS} = 2.5V, I_D = 3A

Q2: N-Channel

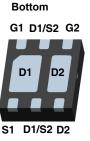
- Max $r_{DS(on)}$ = 100m Ω at V_{GS} = 4.5V, I_D = 4A
- Max r_{DS(on)} = 150mΩ at V_{GS} = 2.5V, I_D = 2A
- Low gate Charge

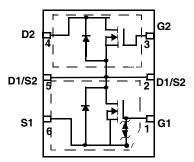




Power 33

MOSFET Maximum Ratings T_A = 25°C unless otherwise noted





FDMC6890NZ is a compact single package solution for DC to

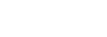
characteristics. Inside the Power 33 package features two

N-channel MOSFETs with low on-state resistance and low gate

charge to maximize the power conversion and switching efficiency. The Q1 switch also integrates gate protection from

October 2006

thermal and switching



Symbol	Parameter	Test Conditions	Туре	Min	Тур	Мах	Units
Off Chara	cteristics						
BV _{DSS}	Drain to Source Breakdown Voltage	$I_{\rm D}$ = 250µA, $V_{\rm GS}$ = 0V	Q1 Q2	20 20			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \mu A$, referenced to 25°C	Q1 Q2		13 12		mV/°C
DSS	Zero Gate Voltage Drain Current	V _{DS} = 16V, V _{GS} = 0V	Q1 Q2			1 1	μA
I _{GSS}	Gate to Source Leakage Current	V_{GS} = ±12V, V_{DS} = 0V	Q1 Q2			±10 ±100	μA nA
On Chara	cteristics						
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu A$		0.6 0.6	0.9 1.0	2 2	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	I_D = 250µA, referenced to 25°C	Q1 Q2		-3 -3		mV/°C
r	Drain to Source On Resistance	$V_{GS} = 4.5V, I_D = 4A$ $V_{GS} = 2.5V, I_D = 3A$	Q1		58 77	68 100	- mΩ
r _{DS(on)}		$V_{GS} = 4.5V, I_D = 4A$ $V_{GS} = 2.5V, I_D = 2A$	Q2		67 102	100 150	
9fs	Forward Transconductance	$V_{DS} = V$, $I_D = 4A$	Q1 Q2		10 7		S
Dynamic	Characteristics						
C _{iss}	Input Capacitance		Q1 Q2		205 190	270 250	pF
C _{oss}	Output Capacitance	V _{DS} = 10V, V _{GS} = 0V, f= 1MHZ	Q1 Q2		60 60	80 80	pF
C _{rss}	Reverse Transfer Capacitance		Q1 Q2		40 35	60 55	pF
R _g	Gate Resistance	f = 1MHz	Q1 Q2		3.3 2.8		Ω
Switching	g Characteristics						
t _{d(on)}	Turn-On Delay Time		Q1 Q2		4 4	10 10	ns
t _r	Rise Time	V_{DD} = 10V, I_D = 4A, R_{GEN} = 6 Ω	Q1 Q2		13 12	22 21	ns
t _{d(off)}	Turn-Off Delay Time		Q1 Q2		10 7	19 14	ns
t _f	Fall Time		Q1 Q2		6 6	12 12	ns
Q _{g(TOT)}	Total Gate Charge at 4.5V	$V_{GS} = 0V \text{ to } 4.5V$	Q1 Q2		2.4 1.8	3.4 2.6	nC

Q_{g(2)}

 Q_gs

 Q_{gd}

Total Gate Charge at 2V

Gate to Source Gate Charge

Gate to Drain "Miller" Charge

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nC

nC

nC

2

 $V_{DD} = 10 V$ $I_D = 4A$ Q1 Q2

Q1

Q2

Q1

Q2

1.4

0.6

0.4

0.5

0.9

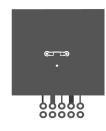
0.8

1.9

8.0

Symbol	Parameter	Test Conditions	Туре	Min	Тур	Max	Units
Drain-Sou	urce Diode Characteristics						
V _{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0V, I_S = 4A$	Q1 Q2		0.94 0.92	1.25 1.25	V
t _{rr}	Reverse Recovery Time	I _F = 4A, di/dt = 100A/s	Q1 Q2		18 17	27 26	ns
Q _{rr}	Reverse Recovery Charge		Q1 Q2		9 10	14 15	nC

Notes:
1: R_{0JA} is determined with the device mounted on a 1in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R_{0JC} is guaranteed by design while R_{0CA} is determined by the user's board design.

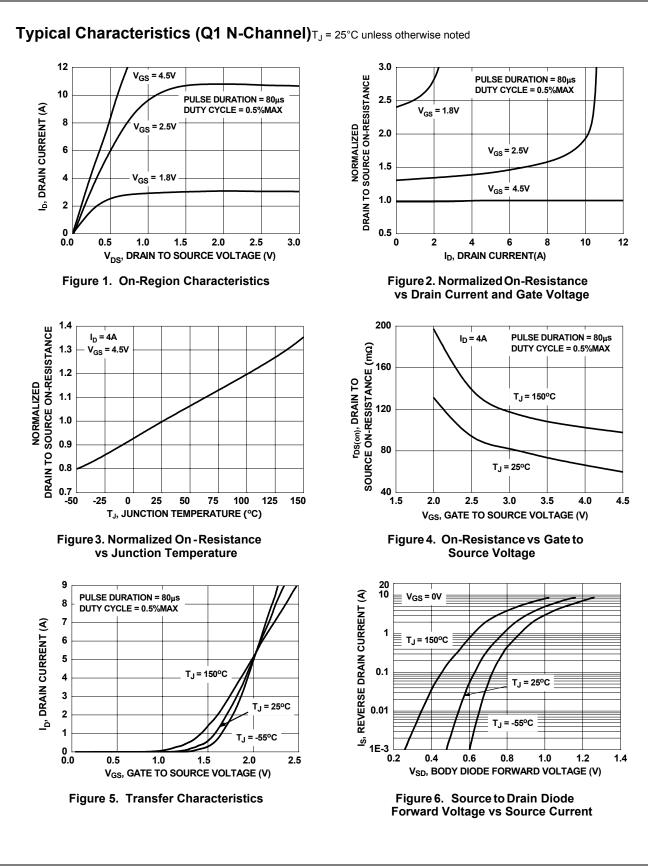


a. 65°C/W when mounted on a 1 in² pad of 2 oz copper

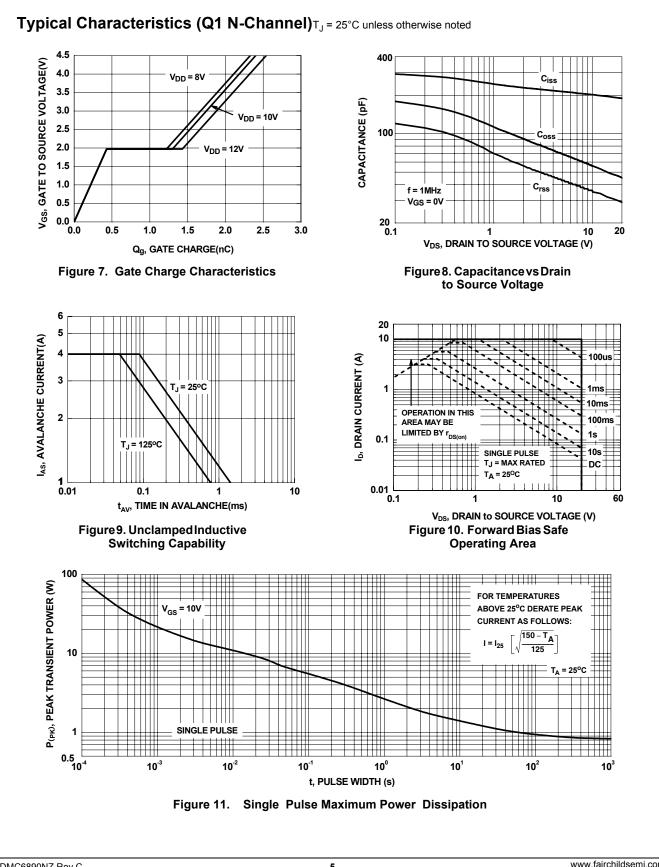
b. 150°C/W when mounted on a minimum pad of 2 oz copper

2: Pulse Test: Pulse Width < 300µs, Duty cycle < 2.0%.





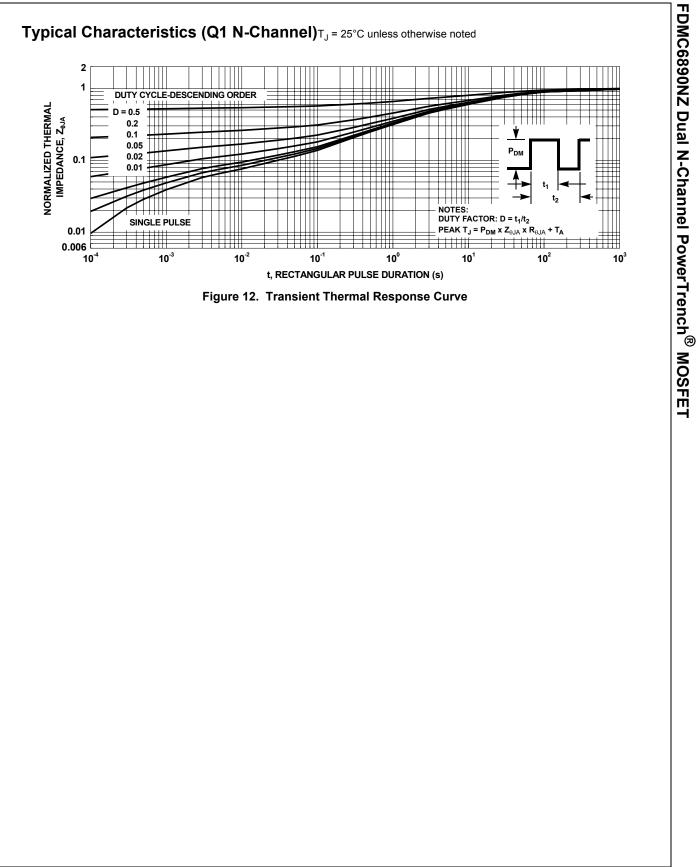
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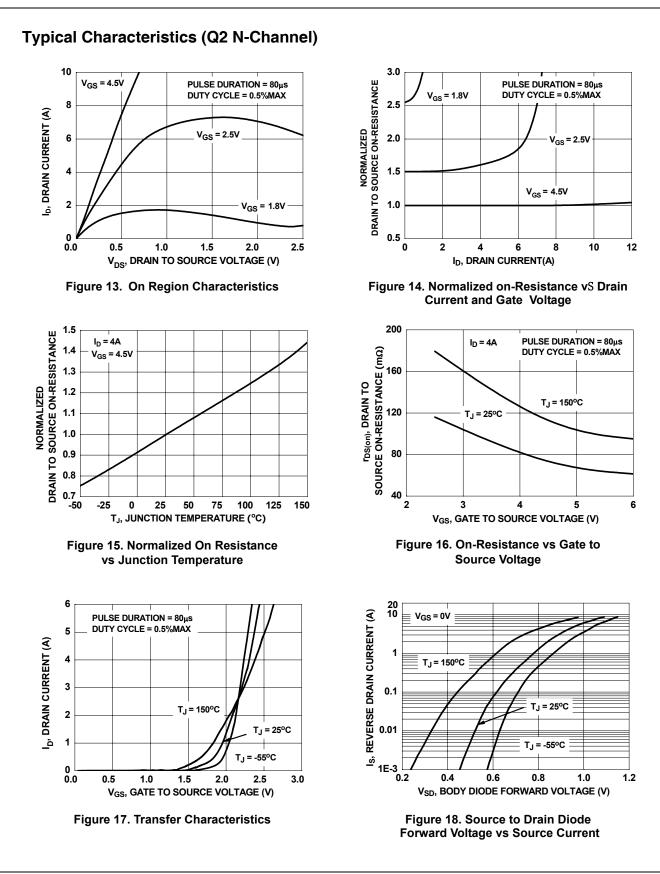
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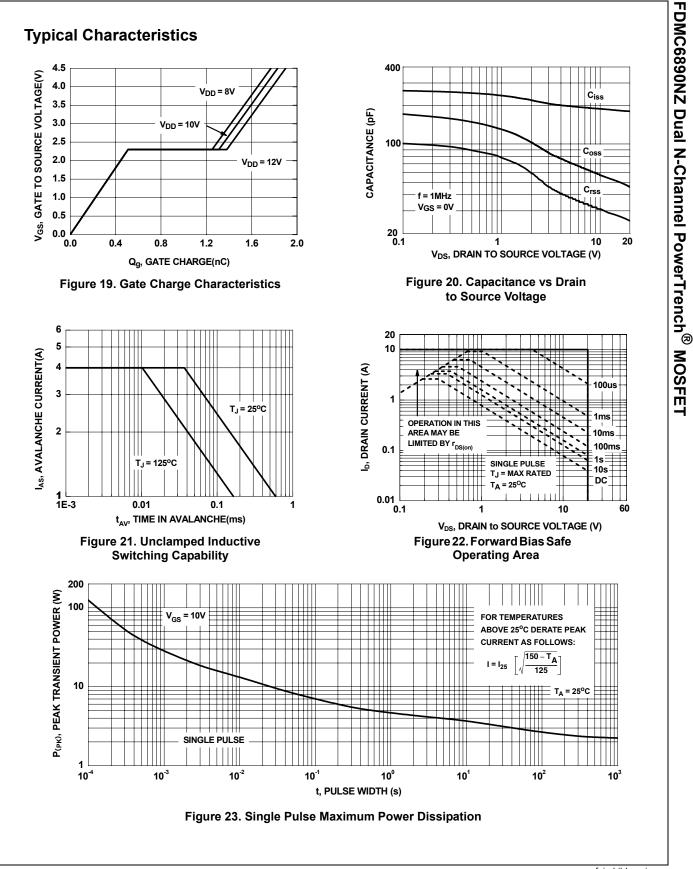
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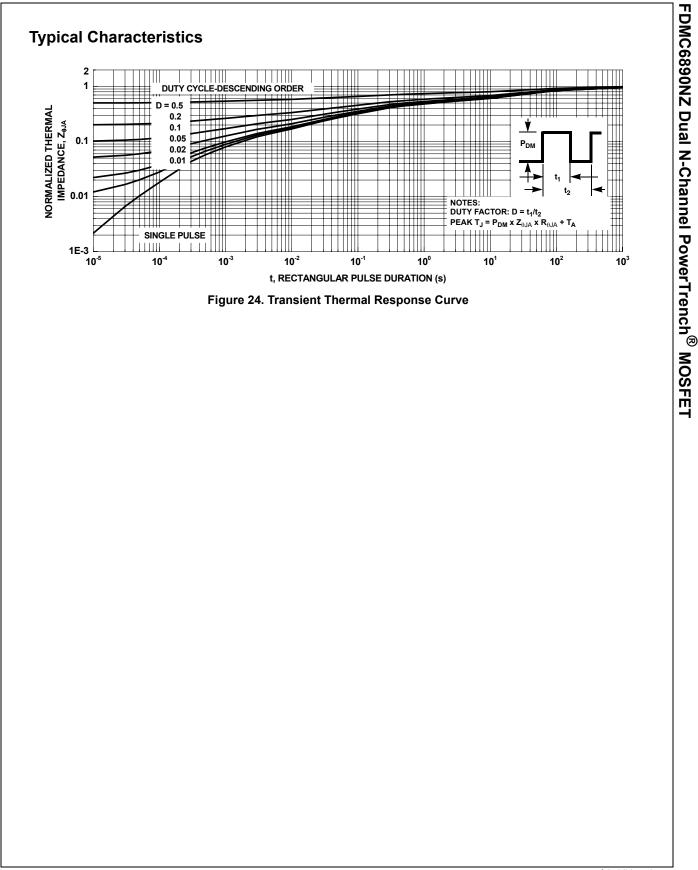
FDMC6890NZ Dual N-Channel PowerTrench[®] MOSFET

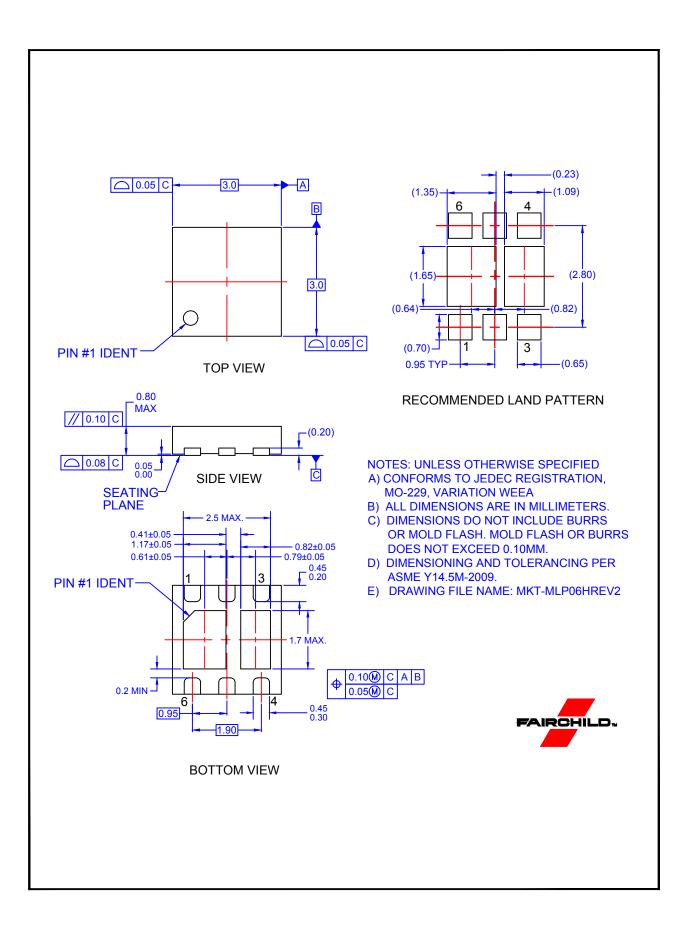


FDMC6890NZ Dual N-Channel PowerTrench[®] MOSFET









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